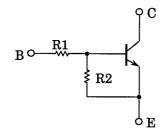
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1107,RN1108,RN1109

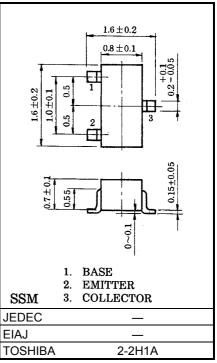
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2107~2109

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1107	10	47
RN1108	22	47
RN1109	47	22



Weight: 2.4mg

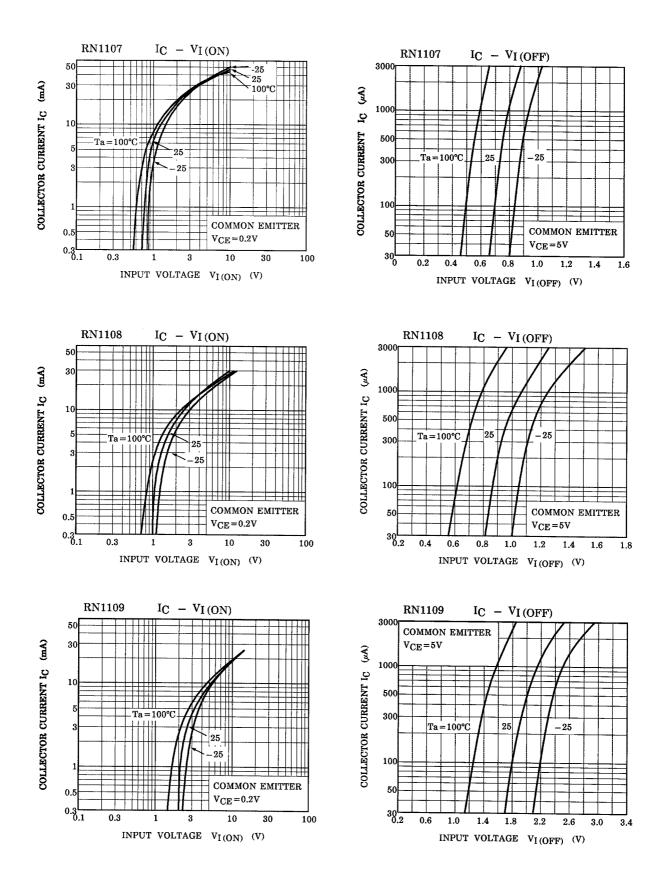
Maximum Ratings (Ta = 25°C)

Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN1107~1109	V _{CBO}	50	V	
Collector-emitter voltage	RN1107~1109	V _{CEO}	50	V	
	RN1107		6	V	
Emitter-base voltage	RN1108	V _{EBO}	7		
	RN1109		15		
Collector current	RN1107~1109	I _c	100	mA	
Collector power dissipation	RN1107~1109	Pc	100	mW	
Junction temperature	RN1107~1109	Тj	150	°C	
Storage temperature range	RN1107~1109	T _{stg}	-55~150	°C	

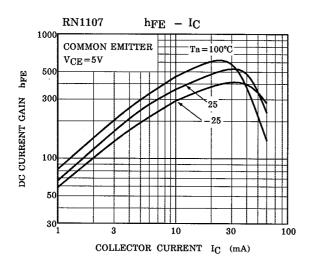
Unit: mm

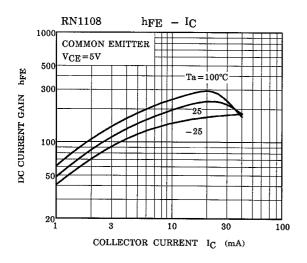
Electrical Characteristics (Ta = 25°C)

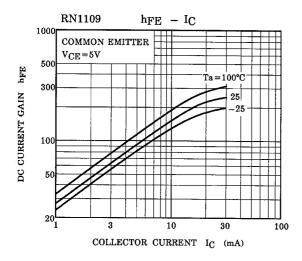
Characteris	tic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1107~1109	I _{CBO}	—	$V_{CB} = 50V, I_E = 0$	_	—	100	nA
	KN1107~1109	I _{CEO}	—	V_{CE} = 50V, I _B = 0	_	_	500	nA
	RN1107		—	$V_{EB} = 6V, I_C = 0$	0.081	_	0.15	
Emitter cut-off current	RN1108	I _{EBO}	_	V _{EB} = 7V, I _C = 0	0.078	_	0.145	mA
	RN1109		—	V _{EB} = 15V, I _C = 0	0.167	_	0.311	
	RN1107	h _{FE}	_	V _{CE} = 5V, I _C = 10mA	80	_	_	
DC current gain	RN1108		_		80	_	_	
	RN1109		_		70	_	_	
Collector-emitter saturation voltage	RN1107~1109	V _{CE (sat)}	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
Input voltage (ON)	RN1107	V _{I (ON)}	—	V _{CE} = 0.2V, I _C = 5mA	0.7	_	1.8	v
	RN1108		_		1.0	_	2.6	
	RN1109		_		2.2	_	5.8	
Input voltage (OFF)	RN1107	VI (OFF)	_	V _{CE} = 5V, I _C = 0.1mA	0.5	_	1.0	v
	RN1108		_		0.6	_	1.16	
	RN1109		_		1.5	_	2.6	
Translation frequency	RN1107~1109	f _T	_	V _{CE} =10V, I _C = 5mA	_	250		MHz
Collector output capacitance	RN1107~1109	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3	6	pF
Input Resistor	RN1107	R1	_		7	10	13	kΩ
	RN1108		_		15.4	22	28.6	
	RN1109		_		32.9	47	61.1	
Resistor Ratio	RN1107	R1/R2	 _		0.191	0.213	0.232	
	RN1108		_		0.421	0.468	0.515	
	RN1109		_		1.92	2.14	2.35	



TOSHIBA







Type Name	Marking
RN1107	Type Name X H H H
RN1108	Type Name XI
RN1109	Type Name XJ UUU

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